

5A, 20V - 200V Surface Mount Schottky Barrier Rectifier

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Guard ring for over-voltage protection
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- Converter

MECHANICAL DATA

- Case: DO-214AB (SMC)
- Molding compound meets UL 94V-0 flammability rating
- Part no. with suffix "H" means AEC-Q101 qualified
- Packing code with suffix "G" means green compound (halogen-free)
- Moisture sensitivity level: level 1, per J-STD-020
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.21 g (approximately)

KEY PARAMETERS					
PARAMETER	VALUE	UNIT			
I _{F(AV)}	5	А			
V _{RRM}	20 - 200	V			
I _{FSM}	120	А			
T _{J MAX}	150	°C			
Package	DO-214AB (SMC)				
Configuration	Single die				





DO-214AB (SMC)

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)											
PARAMETER	SYMBOL	SK	SK	SK	SK	SK	SK	SK	SK	SK	UNIT
	STWBUL	52C	53C	54C	55C	56C	59C	510C	515C	520C	UNIT
Marking code on the device		SK 52C	SK 53C	SK 54C	SK 55C	SK 56C	SK 59C	SK 510C	SK 515C	SK 520C	
Repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	90	100	150	200	V
Reverse voltage, total rms value	V _{R(RMS)}	14	21	28	35	42	63	70	105	140	V
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	90	100	150	200	V
Forward current	I _{F(AV)}					5					Α
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}					120					А
Critical rate of rise of off-state voltage	dV/dt					10,000)				V/µs
Junction temperature	$T_{\rm J}$	- 55 to +150			°C						
Storage temperature	T _{STG}	T _{STG} - 55 to +150					°C				



THERMAL PERFORMANCE						
PARAMETER	SYMBOL	ТҮР	UNIT			
Junction-to-lead thermal resistance per diode	R _{ejl}	17	°C/W			
Junction-to-ambient thermal resistance per diode	R _{eJA}	50	°C/W			

PARAMETER		CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
	SK52C SK53C SK54C		-	0.55	V	
Forward voltage per diode (1)	SK55C SK56C	I _F = 5A, T _J = 25°C	V _F	-	0.75	V
	SK59C SK510C			-	0.85	V
	SK515C SK520C			-	0.95	V
Reverse current @ rated V_R per diode ⁽²⁾	SK52C SK53C SK54C SK55C SK56C	T _J = 25°C	I _R	-	0.5	mA
per diode (~)	SK59C SK510C SK515C SK520C			-	0.3	mA
	SK52C SK53C SK54C		I _R	-	20	mA
Reverse current @ rated V_R per diode ⁽²⁾	SK55C SK56C	Т _J = 100°С		-	10	mA
	er diode ⁽²⁾ SK59C SK510C SK515C SK520C		-	-	mA	
SK52C SK53C SK54C			-	-	mA	
Reverse current @ rated V_R per diode $^{(2)}$	SK55C SK56C		I _R	-	-	mA
per diode ⁽²⁾	SK59C SK510C SK515C SK520C			-	5	mA

Notes:

1. Pulse test with PW=0.3 ms

2. Pulse test with PW=30 ms



ORDERING INFORMATION						
PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING	
		R7	G	SMC	850 / 7" Plastic reel	
		R6		SMC	3,000 / 13" Paper reel	
SK5xxC (Note 1,2)	н	M6		SMC	3,000 / 13" Plastic reel	
(100le 1,2)		V7		Matrix SMC	850 / 7" Plastic reel	
		V6		Matrix SMC	3,000 / 13" Plastic reel	

Note :

1. "xx" defines voltage from 20V (SK52C) to 200V (SK520C)

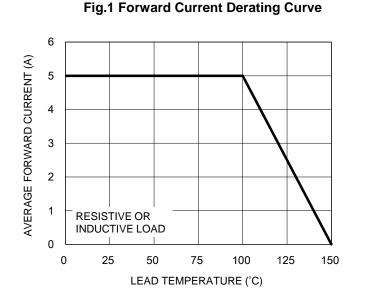
2. Only V6 and V7 are all green compound (halogen free)

EXAMPLE						
EXAMPLE P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION	
SK52CHR7G	SK52C	Н	R7	G	AEC-Q101 qualified Green compound	



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$



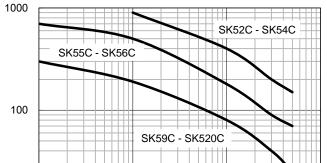


Fig.2 Typical Junction Capacitance

REVERSE VOLTAGE (V) REVERSE VOLTAGE (V)

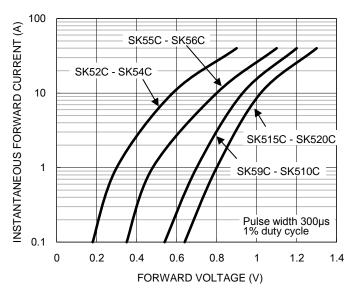
10

100

100 INSTANTANEOUS REVERSE CURRENT (mA) T_=125°C 10 1 T_=75°C ≦ 0.1 T_=25°C 0.01 SK52C-SK54C ---SK55C-SK520C 0.001 20 40 140 0 60 80 100 120 PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

Fig.3 Typical Reverse Characteristics

Fig.4 Typical Forward Characteristics



CAPACITANCE (pF)

10

0.1

f=1.0MHz

Vsig=50mVp-p

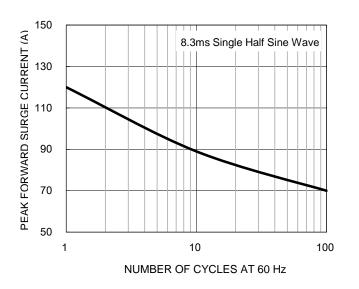
1



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

Fig.5 Maximum Non-repetitive Forward Surge Current



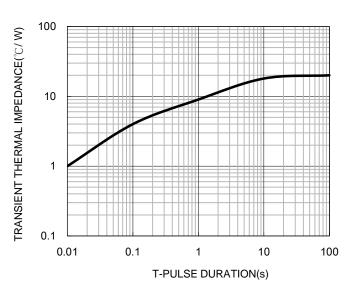
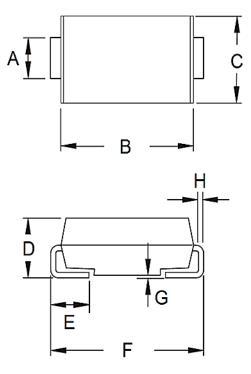


Fig.6 Typical Transient Thermal Characteristics



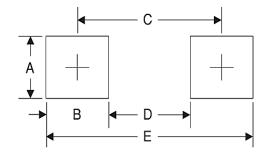
PACKAGE OUTLINE DIMENSIONS

DO-214AB (SMC)



	DIM. Unit (mm)		Unit (inch)		
DIN.			Min.	Max.	
А	2.90	3.20	0.114	0.126	
В	6.60	7.11	0.260	0.280	
С	5.59	6.22	0.220	0.245	
D	2.00	2.62	0.079	0.103	
E	1.00	1.60	0.039	0.063	
F	7.75	8.13	0.305	0.320	
G	0.10	0.20	0.004	0.008	
Н	0.15	0.31	0.006	0.012	

SUGGESTED PAD LAYOUT

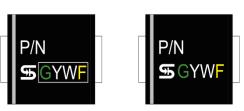


Symbol	Unit (mm)	Unit (inch)
А	3.30	0.130
В	2.50	0.098
С	6.80	0.268
D	4.40	0.173
E	9.40	0.370

MARKING DIAGRAM

Matrix SMC





- G =Green Compound
- YW =Date Code
- F =Factory Code



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